



### PowerDI5060-8

## **Product Summary**

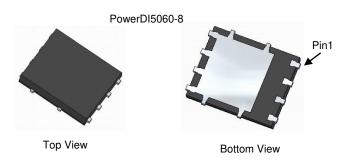
BV <sub>DSS</sub>	RDS(ON) Max	Qg Typ	I⊳ Tc = +25°C
40V	2.7mΩ @ V <sub>GS</sub> = 10V	68.6nC	100A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine management systems
- Body control electronics
- DC-DC converters

Site 1:



Site 2:

Notes:

PowerDI5060-8 (SWP) (Type UX)



Top View

Bottom View

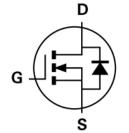


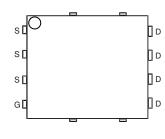
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub> Minimizes Power Losses
- Low Q<sub>g</sub> Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4004SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

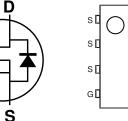
- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

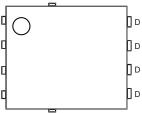




Internal Schematic







Internal Schematic

Top View Pin Configuration

# Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMTH4004SPSQ-13	PowerDI5060-8	2,500	Tape & Reel	
DMTH4004SPSQ-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

Pin1

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

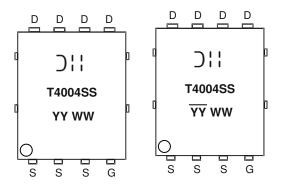
G

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**



) = Manufacturer's Marking T4004SS = Product Type Marking Code YYWW = Date Code Marking YY or  $\overrightarrow{YY}$  = Year (ex: 23 = 2023) WW = Week (01 to 53)

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	40	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 5)	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	31 26	А
	Tc = +25°C		100	А
Continuous Drain Current (Note 6)	Tc = +100°C (Note 8)	ID	100	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	350	A
Maximum Continuous Body Diode Forward Current (Note 5)		ls	100	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	350	A
Avalanche Current, L=0.2mH		las	45	A
Avalanche Energy, L=0.2mH		Eas	200	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	3.6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	41	°C/W
Total Power Dissipation (Note 6)	$T_{\rm C} = +25^{\circ}{\rm C}$	PD	167	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single- sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady state.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

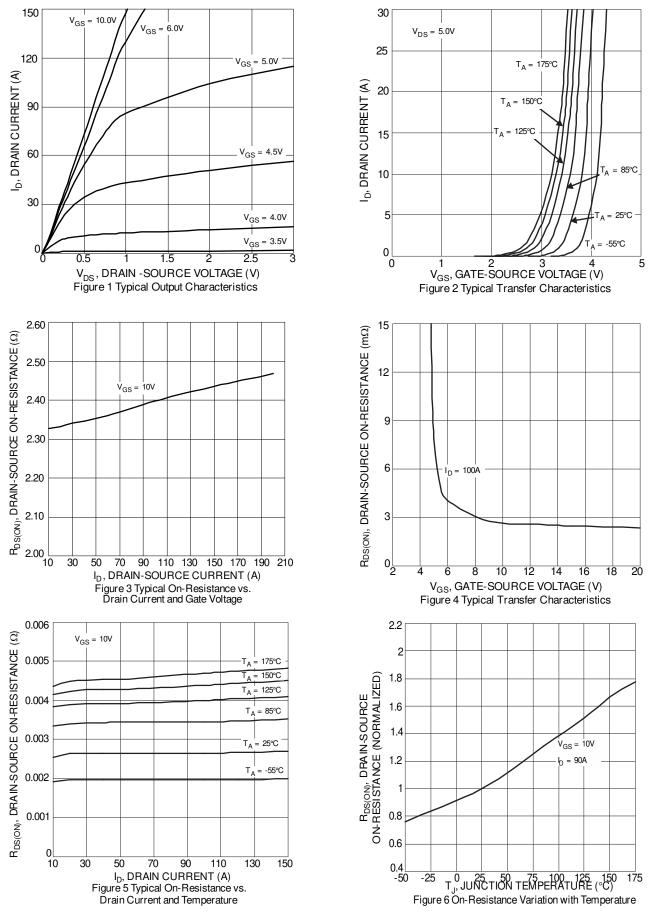
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIII	Тур	IVIAX	Unit	Test Condition	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		_	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2	_	4	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	2.3	2.7	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 90A	
Diode Forward Voltage	Vsd	_	0.9	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	4,305	—	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss		1,441	—			
Reverse Transfer Capacitance	Crss		102	-			
Gate Resistance	Rg		0.77	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	68.6	—			
Gate-Source Charge	Qgs	_	16.8	—	nC	V <sub>DD</sub> = 20V, I <sub>D</sub> = 90A, V <sub>GS</sub> = 10V	
Gate-Drain Charge	Q <sub>gd</sub>		14.2	—			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.5	—			
Turn-On Rise Time	tR	_	6.7	—	ns	$\label{eq:VDD} \begin{array}{l} V_{DD} = 20V, \ V_{GS} = 10V, \\ I_D = 90A, \ R_G = 3.5\Omega \end{array}$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		26.4	—			
Turn-Off Fall Time	tF		8.1	—			
Body Diode Reverse Recovery Time	trr	_	52.4	—	ns		
Body Diode Reverse Recovery Charge	QRR	—	78.2	—	nC	l⊧ = 50A, di/dt = 100A/µs	

 Notes:
 7. Short duration pulse test used to minimize self-heating effect.

 8. Guaranteed by design. Not subject to production testing

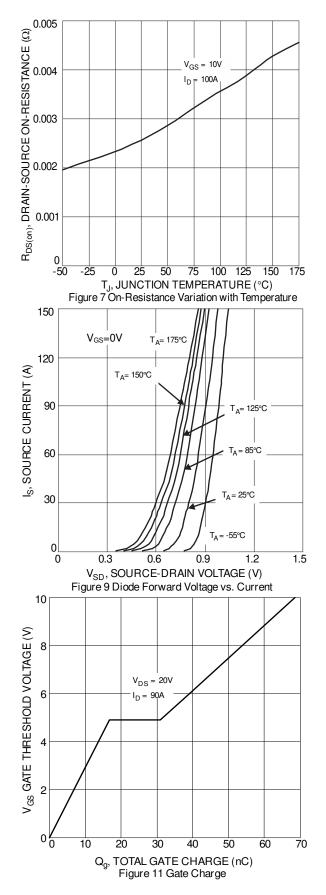


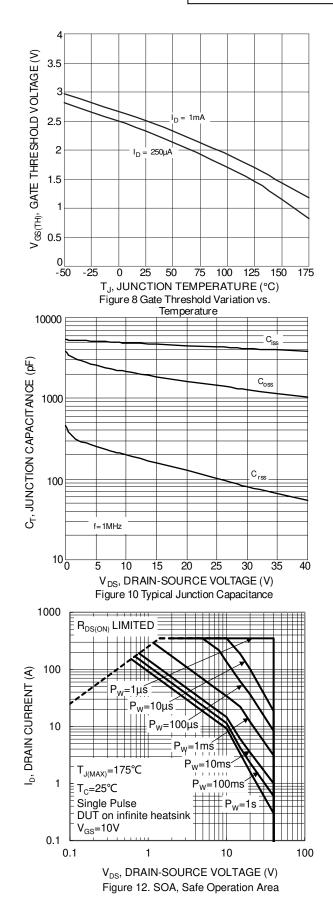
# DMTH4004SPSQ



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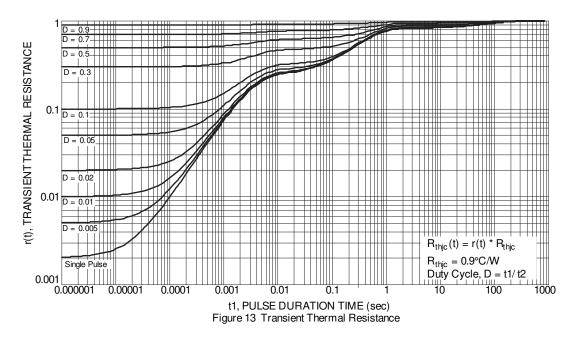






DMTH4004SPSQ Document number: DS37562 Rev. 5 - 2







# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

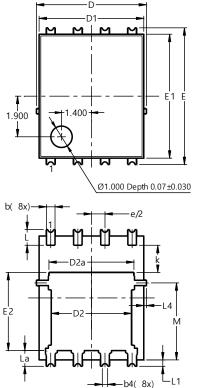
D Detail A D1 θ( 4X) С A1 E1 e (+θ1 ( 4X) b( 8X) e/2 b2 ( 4X) Δ Ш Ш D b3 ( 4X) E3 E2 M1 Detail A I G

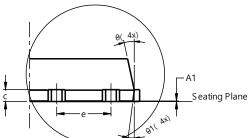
	PowerD	15060-8		
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	-	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D		5.15 BSC		
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
E	(	6.15 BSC	;	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е		1.27 BSC		
G	0.51	0.71	0.61	
К	0.51	-	_	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
М	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
Al	All Dimensions in mm			

Site 2:

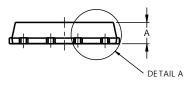
#### PowerDI5060-8 (SWP) (Type UX)

PowerDI5060-8





DETAIL A



PowerDI5060-8 (SWP) (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	(	).25REF	-	
С	0.230	0.330	0.277	
D	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
E	6	.40 BS0		
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195		4.395	
е		.27BSC	)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0.050REF			
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	Dimensi	ions in	mm	

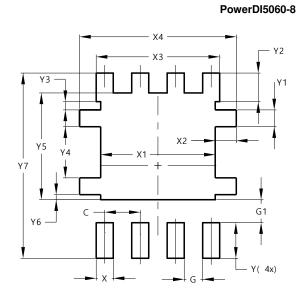
DMTH4004SPSQ Document number: DS37562 Rev. 5 - 2



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

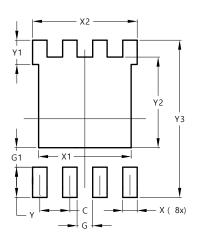
#### Site 1:



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
¥7	6.610

Site 2:

### PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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